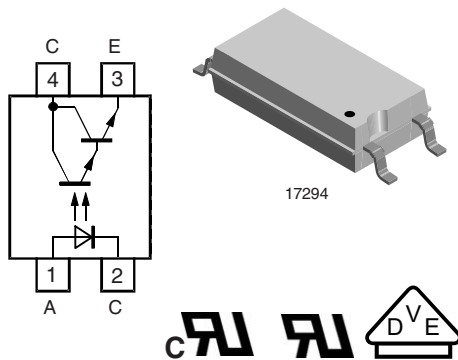


Optocoupler, Photodarlington Output, SOP-4L, Long Mini-Flat Package



FEATURES

- Low profile package
- Darlington output
- Extra low coupling capacity - typical 0.2 pF
- High common mode rejection
- Creepage current resistance according to VDE 0303/IEC 60112 comparative tracking index: CTI \geq 175
- Thickness through insulation \geq 0.75 mm
- Creepage distance $>$ 8 mm
- Tested acc. 60950: AM4: 1997 clause 2.9.6.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


**RoHS
COMPLIANT**

DESCRIPTION

The TCLD1000 consists of a darlington phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead SO6L package.

The elements are mounted on one leadframe, provide a fixed distance between input and output for highest safety requirements.

AGENCY APPROVALS

- UL1577, file no. E76222 system code W, double protection
- CSA 22.2 bulletin 5A, double protection
- BSI IEC 60950 IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending

APPLICATIONS

- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Reinforced isolation provides circuit protection against electrical shock (safety class II)
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I - IV at mains voltage \leq 300 V
 - for appl. class I - III at mains voltage \leq 600 V according to DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending.

ORDER INFORMATION

PART	REMARKS
TCLD1000	CTR $>$ 600 %, SMD-4

ABSOLUTE MAXIMUM RATINGS (1)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10 \mu s$	I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Junction temperature		T_j	125	$^{\circ}C$
OUTPUT				
Collector emitter voltage		V_{CEO}	35	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	80	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 ms$	I_{CM}	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	$^{\circ}C$

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Isolation test voltage (RMS)		V_{ISO}	5000	V_{RMS}
Total power dissipation		P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 125	°C
Soldering temperature ⁽²⁾		T_{sld}	260	°C

Note

⁽¹⁾ $T_{amb} = 25\text{ °C}$, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 20\text{ mA}$	V_F		1.1	1.4	V
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_j		50		pF
OUTPUT						
Collector emitter voltage	$I_C = 1\text{ mA}$	V_{CEO}	32			V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	V_{ECO}	7			V
Collector emitter cut-off current	$V_{CE} = 10\text{ V}$, $I_F = 0\text{ A}$, $E = 0$	I_{CEO}		15	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 20\text{ mA}$, $I_C = 5\text{ mA}$	V_{CEsat}			1.0	V
Cut-off frequency	$V_{CE} = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	f_c		10		kHz
Coupling capacitance	$f = 1\text{ MHz}$	C_k		0.3		pF

Note

$T_{amb} = 25\text{ °C}$, unless otherwise specified.

Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$V_{CE} = 2\text{ V}$, $I_F = 1\text{ mA}$	CTR	600	800		%

MAXIMUM SAFETY RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward current		I_F			130	mA
OUTPUT						
Power dissipation	$T_{amb} \leq 25\text{ °C}$	P_{diss}			265	mW
COUPLER						
Rated impulse voltage		V_{IOTM}			8	kV
Safety temperature		T_{si}			150	°C

Note

According to DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending (see figure 1). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1$ s	V_{pd}	2.0			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60$ s, $t_{test} = 10$ s, (see figure 2)	V_{IOTM}	8			kV
		V_{pd}	1.68			kV
Insulation resistance	$V_{IO} = 500$ V	R_{IO}	10^{12}			Ω
	$V_{IO} = 500$ V, $T_{amb} = 100$ °C	R_{IO}	10^{11}			Ω
	$V_{IO} = 500$ V, $T_{amb} = 150$ °C (construction test only)	R_{IO}	10^9			Ω

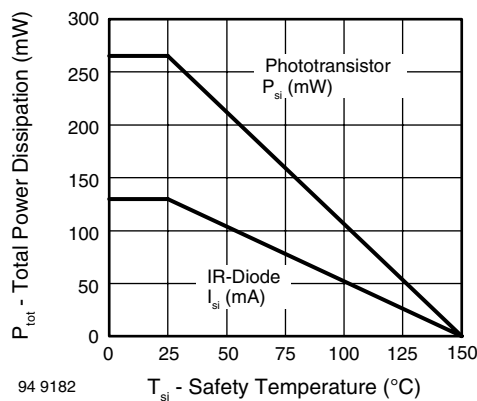


Fig. 1 - Derating Diagram

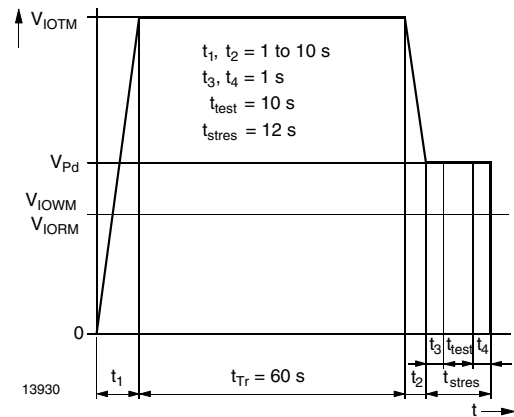


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-; IEC 60747

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	$V_{CE} = 2$ V, $I_C = 10$ mA, $R_L = 100$ Ω , (see figure 3)	t_r		300		μ s
Turn-off time	$V_{CE} = 2$ V, $I_C = 10$ mA, $R_L = 100$ Ω , (see figure 3)	t_{off}		250		μ s

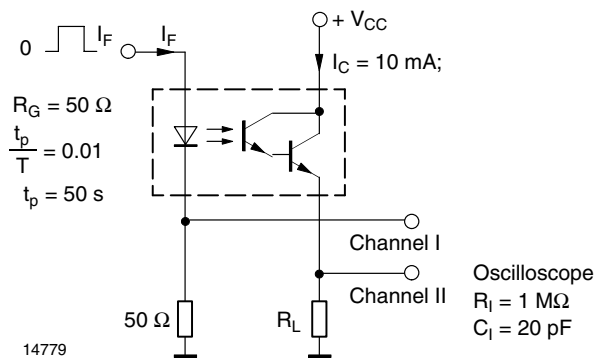


Fig. 3 - Test Circuit, Non-Saturated Operation

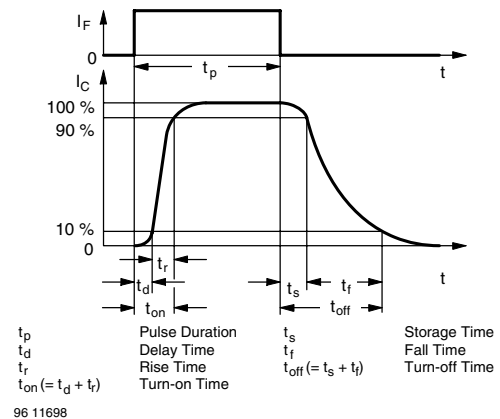


Fig. 4 - Switching Times

TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

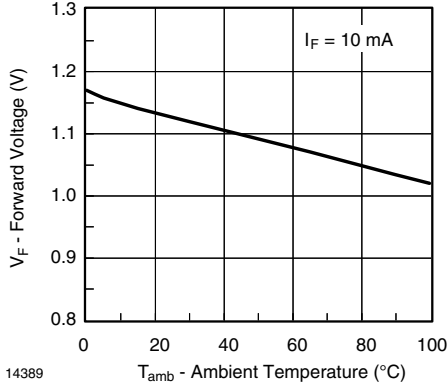


Fig. 5 - Forward Voltage vs. Ambient Temperature

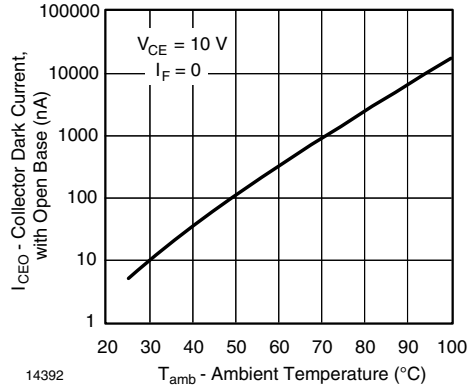


Fig. 8 - Collector Dark Current vs. Ambient Temperature

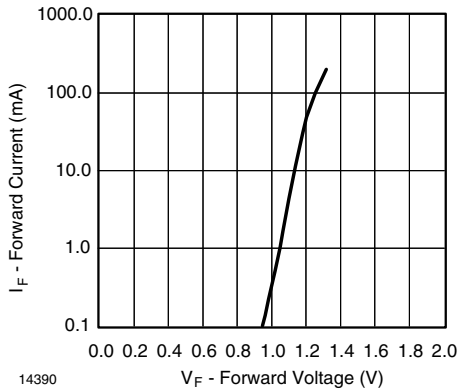


Fig. 6 - Forward Current vs. Forward Voltage

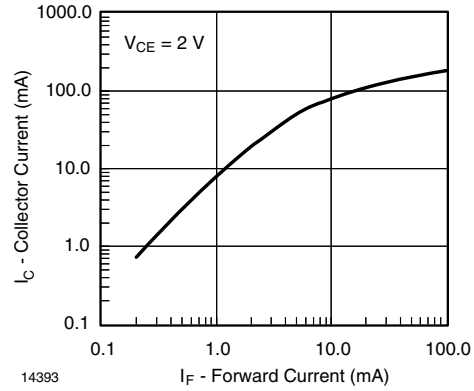


Fig. 9 - Collector Current vs. Forward Current

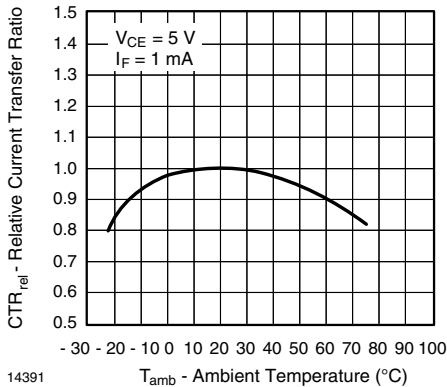


Fig. 7 - Relative Current Transfer Ratio vs. Ambient Temperature

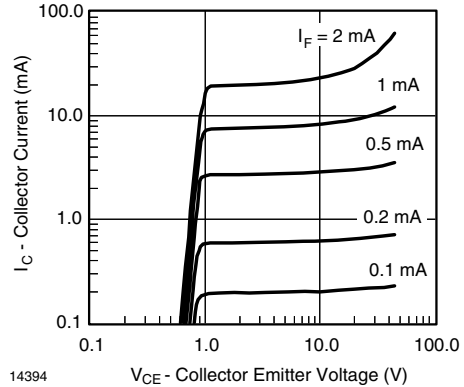


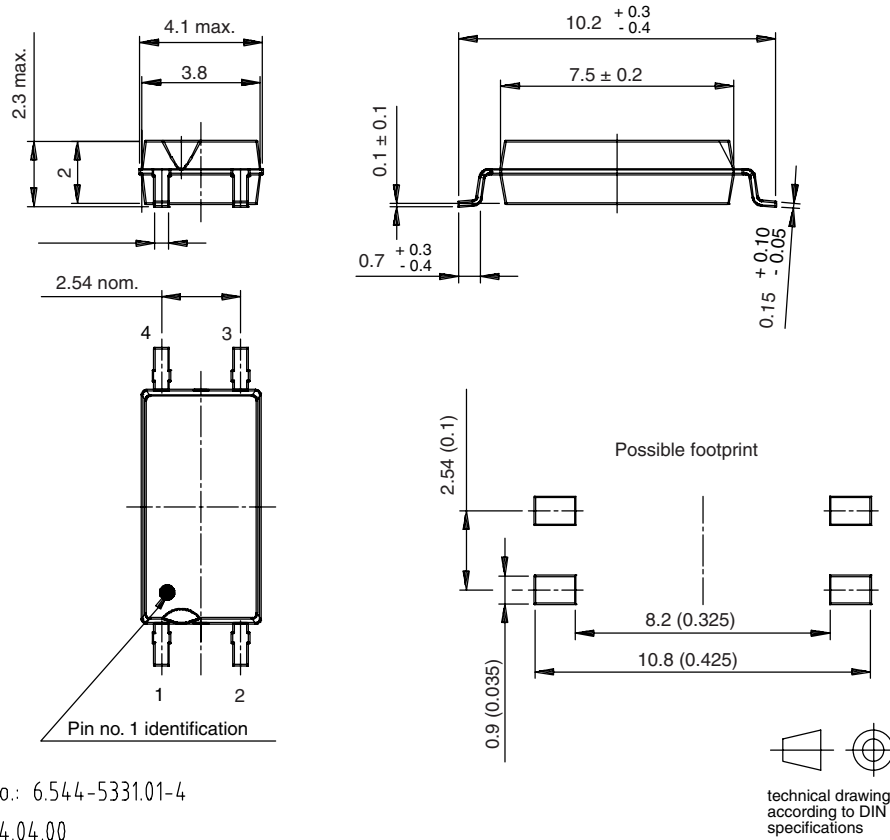
Fig. 10 - Collector Current vs. Collector Emitter Voltage



Optocoupler, Photodarlington Output,
SOP-4L,
Long Mini-Flat Package

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5331.01-4

Issue: 1; 04.04.00

15243

Vishay Semiconductors Optocoupler, Photodarlington Output,
SOP-4L,
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OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

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Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
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